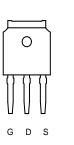


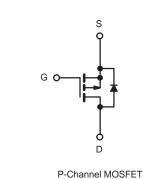
P-Channel 30-V (D-S) MOSFET

| PRODUCT SUMMARY | | | | | | |
|---------------------|----------------------------------|--|-------|--|--|--|
| V _{DS} (V) | R _{DS(on)} (Ω) | R _{DS(on)} (Ω) I _D (A) | | | | |
| - 30 | 0.056 at V_{GS} = - 10 V | - 15 ^d | 22 nC | | | |
| - 30 | 0.073 at V _{GS} =-4.5 V | - 15 ^d | 22110 | | | |

TO-251



Top View



FEATURES

- DT-Trench Power MOSFET
- 100% R_g Tested
 100% UIS Tested

APPLICATIONS

- Notebook Battery Charging
- Notebook Adapter Switch



| ABSOLUTE MAXIMUM RATINGS T | $_{\rm A}$ = 25 °C, unless othe | erwise noted | | |
|---|-----------------------------------|-----------------|------------------------|----|
| Parameter | Symbol | Limit | Unit | |
| Drain-Source Voltage | V _{DS} | - 30 | V | |
| Gate-Source Voltage | | V _{GS} | ± 25 | v |
| | T _C = 25 °C | | - 15 ^d | |
| Continuous Drain Current ($T_1 = 150 \text{ °C}$) | T _C = 70 °C | | - 13 ^d | |
| | T _A = 25 °C | I _D | - 10.6 ^{a, b} | |
| | T _A = 70 °C | 1 [| - 8.6 ^{a, b} | A |
| Pulsed Drain Current | I _{DM} | - 50 | | |
| Continuous Source-Drain Diode Current | T _C = 25 °C | I _S | - 15 ^d | |
| Continuous Source-Drain Diode Current | T _A = 25 °C | 'S | - 3.0 ^{a, b} | |
| Avalanche Current | | I _{AS} | - 20 | |
| Single-Pulse Avalanche Energy | L = 0.1 mH | E _{AS} | 20 | mJ |
| | T _C = 25 °C | | 52 | |
| Maximum Dawar Dissipation | T _C = 70 °C | P _D | 33 | w |
| Maximum Power Dissipation | T _A = 25 °C | | 3.7 ^{a, b} | vv |
| | T _A = 70 °C | | 2.4 ^{a, b} | |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | - 55 to 150 | <u></u> | |
| Soldering Recommendations (Peak Temperature) | | 260 | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|-----------------------------|--------------|-------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Maximum Junction-to-Ambient | t ≤ 10 s | R _{thJA} | 26 | 33 | °C/W |
| Maximum Junction-to-Case | Steady State | R _{thJC} | 1.9 | 2.4 | 0/11 |

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. t = 10 s.

c. Maximum under Steady State conditions is 81 °C/W.d. Package limited.

DTL15P03

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| SPECIFICATIONS $T_J = 25 \ ^{\circ}C$ | 1 | | - | 1 | | | |
|---|-------------------------|---|------------|--------|-------|-------|--|
| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit | |
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0 V, I_D = -250 \mu A$ | - 30 | | | V | |
| V _{DS} Temperature Coefficient | $\Delta V_{DS}/T_{J}$ | I _D = - 250 μA | | - 31 | | mV/°C | |
| V _{GS(th)} Temperature Coefficient | $\Delta V_{GS(th)}/T_J$ | | | 5.5 | | | |
| Gate-Source Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$ | - 1.0 | | - 3.0 | V | |
| Gate-Source Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 25 V$ | | | ± 100 | nA | |
| Zara Cata Valtaga Drain Current | la a a | $V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | | - 1 | μA | |
| Zero Gate Voltage Drain Current | IDSS | $V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$ | | | - 5 | | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \ge -10 \text{ V}, \text{ V}_{GS} = -10 \text{ V}$ | - 30 | | | А | |
| | Para | V _{GS} = - 10 V, I _D = - 10 A | 0.056 0.06 | | 0.062 | | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = - 4.5 V, I _D = - 7 A | | 0.073 | 0.081 | Ω | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = - 10 V, I _D = - 10 A | | 23 | | S | |
| Dynamic ^b | | | | • | • | | |
| Input Capacitance | C _{iss} | | | 1960 | | pF | |
| Output Capacitance | C _{oss} | V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz | | 380 | | | |
| Reverse Transfer Capacitance | C _{rss} | | | 325 | | | |
| Total Gate Charge | Q _g | $V_{DS} = -15 \text{ V}, \text{ V}_{GS} = -10 \text{ V}, \text{ I}_{D} = -10 \text{ A}$ | 43 | 65 | | | |
| | | | | 22 | 33 | nC | |
| Gate-Source Charge | Q _{gs} | V _{DS} = - 15 V, V _{GS} = - 4.5 V, I _D = - 10 A | | 6 | | | |
| Gate-Drain Charge | Q _{gd} | | | 11 | | | |
| Gate Resistance | R _g | f = 1 MHz | 0.3 | 1.3 | 2.5 | Ω | |
| Turn-On Delay Time | t _{d(on)} | | | 11 | 22 | | |
| Rise Time | t _r | V_{DD} = - 15 V, R _L = 3 Ω | | 13 | 25 | - | |
| Turn-Off DelayTime | t _{d(off)} | $I_D \cong$ - 5 A, V_{GEN} = - 10 V, R_g = 1 Ω | | 32 | 50 | | |
| Fall Time | t _f | | | 9 | 18 | | |
| Turn-On Delay Time | t _{d(on)} | | | 44 | 70 | ns | |
| Rise Time | t _r | V_{DD} = - 15 V, R _L = 3 Ω | | 100 | 160 | - | |
| Turn-Off DelayTime | t _{d(off)} | $I_D \cong$ - 5 A, V_{GEN} = - 4.5 V, R_q = 1 Ω | | 28 | 50 | | |
| Fall Time | t _f | | | 15 | 30 | | |
| Drain-Source Body Diode Characterist | tics | | | | | | |
| Continous Source-Drain Diode Current | ۱ _s | T _C = 25 °C | | | - 15 | | |
| Pulse Diode Forward Current | I _{SM} | - | | | - 50 | A | |
| Body Diode Voltage | V _{SD} | I _S = - 2 A, V _{GS} = 0 V | | - 0.75 | - 1.2 | V | |
| Body Diode Reverse Recovery Time | t _{rr} | | | 28 | 45 | ns | |
| Body Diode Reverse Recovery Charge | Q _{rr} | | | 20 | 40 | nC | |
| Reverse Recovery Fall Time | t _a | I _F = - 2 A, dl/dt = 100 A/μs, T _J = 25 °C | | 13 | | ns | |
| Reverse Recovery Rise Time | t _b | 1 | | 15 | | | |

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

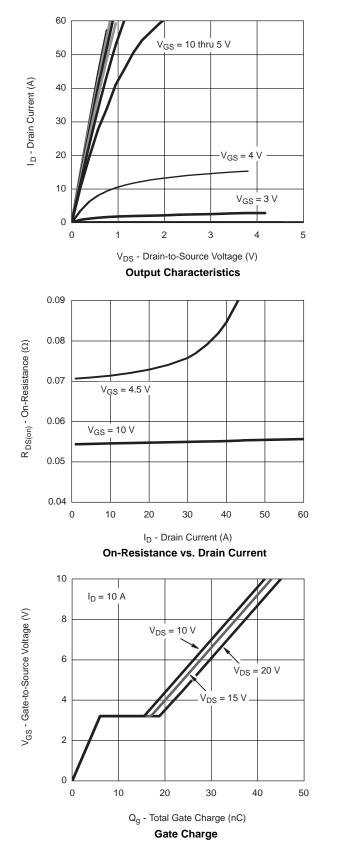
b. Guaranteed by design, not subject to production testing.

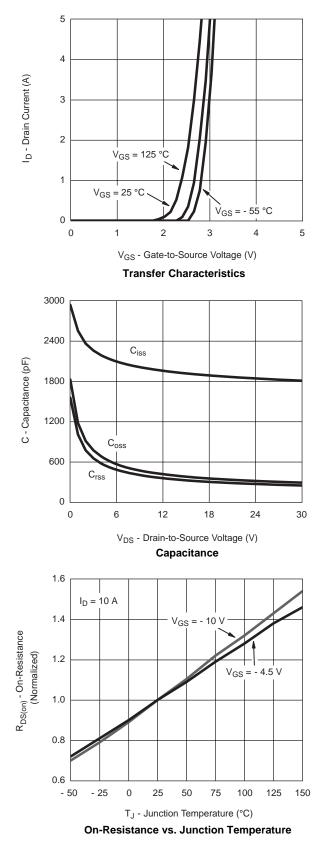
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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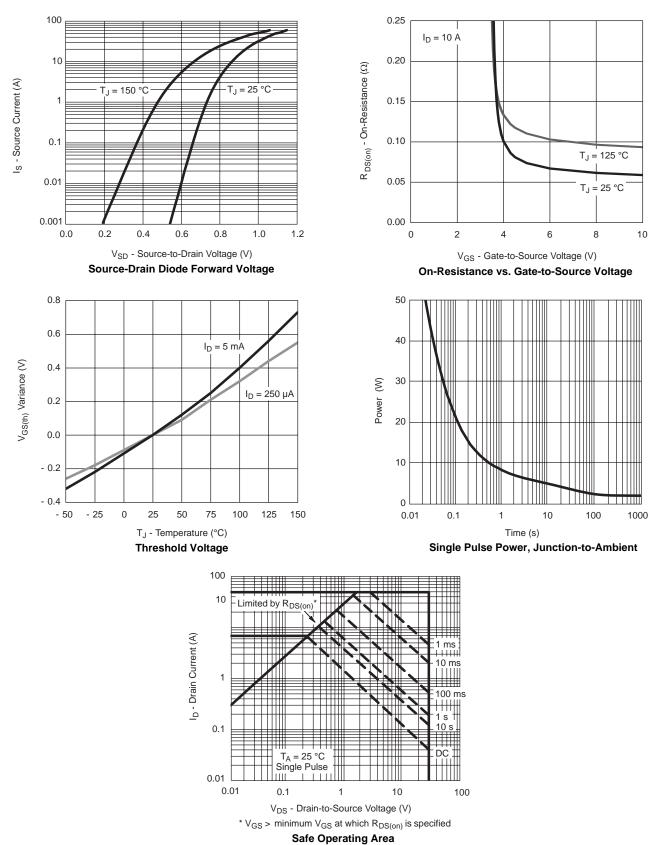
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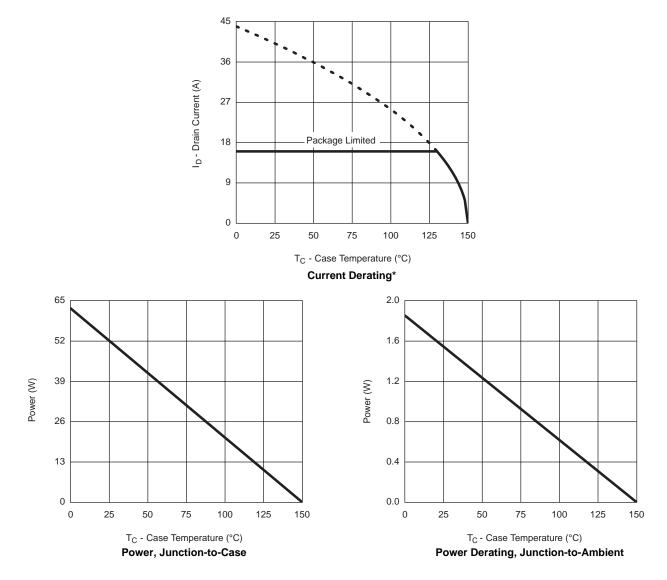




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

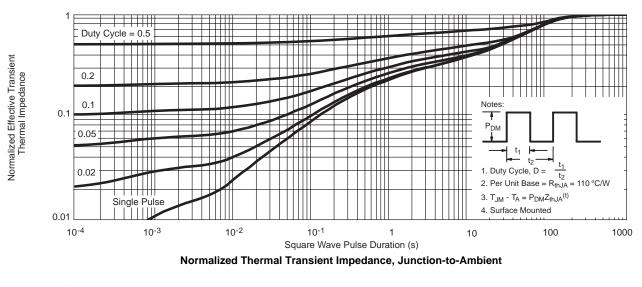


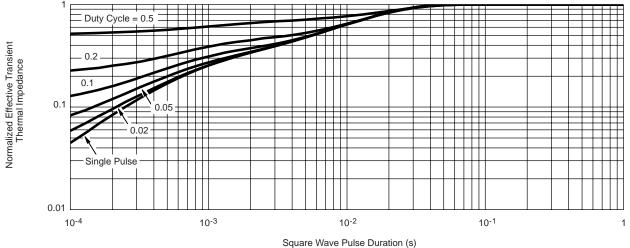
MOSFET TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max)}$ = 175 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

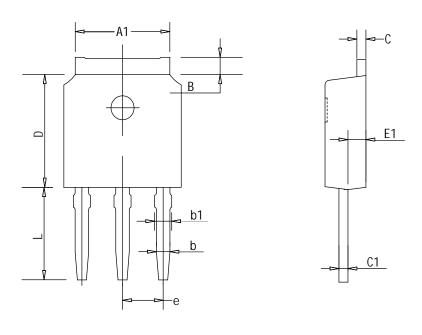
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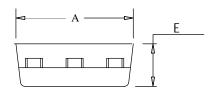




Normalized Thermal Transient Impedance, Junction-to-Case

TO-251 PACKAGE OUTLINE





COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

| SYMBOL | MIN | TYP | MAX |
|--------|------|------|------|
| А | 6.30 | 6.60 | 6.90 |
| A1 | 5.00 | 5.30 | 5.60 |
| В | 0.80 | 1.00 | 1.20 |
| С | 0.40 | 0.50 | 0.60 |
| C1 | 0.40 | 0.50 | 0.60 |
| D | 5.80 | 6.10 | 6.40 |
| E | 2.10 | 2.30 | 2.50 |
| E1 | 0.80 | 1.00 | 1.20 |
| L | 4.50 | 5.00 | 5.50 |
| e | 2.10 | 2.30 | 2.50 |
| b | 0.66 | 0.76 | 0.86 |
| b1 | 0.66 | 0.86 | 1.06 |



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